

### **STAP85025**

# RF power transistor, LdmoST plastic family N-channel enhancement-mode lateral MOSFETs

**Target specification** 

#### **Features**

- Excellent thermal stability
- Common source configuration
- P<sub>OUT</sub> = 25 W with 15.7 dB gain @ 870 MHz / 13.6 V
- Plastic package
- ESD protection
- In compliance with the 2002/95/EC European directive

#### **Description**

The STAP85025 is a common source N-channel, enhancement-mode lateral field-effect RF power transistor. It is designed for high gain, broadband commercial and industrial applications. It operates at 13.6 V in common source mode at frequencies of up to 1 GHz. STAP85025 boasts the excellent gain, linearity and reliability of ST's latest LDMOS technology mounted in STAP ST advanced PowerSO-10RF package. STAP85025's superior linearity performance makes it an ideal solution for car mobile radio.

The STAP ST plastic package was designed to offer high reliability and high power capability. It has been specially optimized for RF needs and offers excellent RF performances and ease of assembly.

Mounting recommendations are available in www.st.com/rf/ (look for application note AN1294)

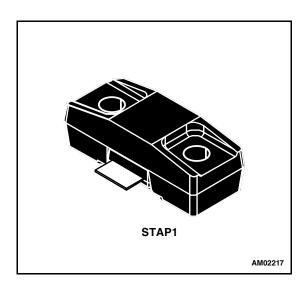


Figure 1. Pin connection

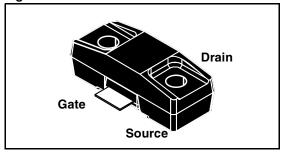


Table 1. Device summary

Order code	Package	Packaging
STAP85025	STAP1	Tube

July 2009 Doc ID 15795 Rev 2 1/12

This is preliminary information on a new product foreseen to be developed. Details are subject to change without notice.

www.st.com

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STAP85025 Electrical data

### 1 Electrical data

### 1.1 Maximum ratings

Table 2. Absolute maximum ratings ( $T_{CASE} = 25$  °C)

Symbol	Parameter	Value	Unit
V <sub>(BR)DSS</sub>	Drain-source voltage	40	V
$V_{GS}$	Gate-source voltage	-0.5 to +15	V
I <sub>D</sub>	Drain current 7		Α
P <sub>DISS</sub>	Power dissipation (@ T <sub>C</sub> = 70 °C) 79		W
TJ	Max. operating junction temperature 165		°C
T <sub>STG</sub>	Storage temperature -65 to +150		°C

### 1.2 Thermal data

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R <sub>thJC</sub>	Junction - case thermal resistance	1.2	°C/W

Electrical characteristics STAP85025

### 2 Electrical characteristics

$$T_{CASE} = +25$$
 °C

#### 2.1 Static

Table 4. Static

Symbol	Test conditions			Min	Тур	Max	Unit
I <sub>DSS</sub>	V <sub>GS</sub> = 0 V	V <sub>DS</sub> = 25 V				1	μΑ
I <sub>GSS</sub>	V <sub>GS</sub> = 5 V	$V_{DS} = 0 V$				1	μΑ
V <sub>GS(Q)</sub>	V <sub>DS</sub> = 10 V	I <sub>D</sub> = 300 mA			4.1		V
V <sub>DS(ON)</sub>	V <sub>GS</sub> = 10 V	I <sub>D</sub> = 1 A		_	0.27	0.31	٧
C <sub>ISS</sub>	V <sub>GS</sub> = 0 V	V <sub>DS</sub> = 12.5 V	f = 1 MHz		55		pF
C <sub>OSS</sub>	V <sub>GS</sub> = 0 V	V <sub>DS</sub> = 12.5 V	f = 1 MHz		40		pF
C <sub>RSS</sub>	V <sub>GS</sub> = 0 V	V <sub>DS</sub> = 12.5 V	f = 1 MHz		1.5		pF

### 2.2 Dynamic

Table 5. Dynamic

Symbol	Test conditions	Min	Тур	Max	Unit
P3dB	$V_{DD} = 13.6 \text{ V}, I_{DQ} = 300 \text{ mA}$ f = 870 MHz	25	30		W
G <sub>P</sub>	$V_{DD} = 13.6 \text{ V}, I_{DQ} = 300 \text{ mA}, P_{OUT} = 10 \text{ W}, f = 870 \text{ MHz}$	15	17.3		dB
h <sub>D</sub>	$V_{DD} = 13.6 \text{ V}, I_{DQ} = 300 \text{ mA}, P_{OUT} = P3dB, f = 870 \text{ MHz}$	60	66	_	%
Load mismatch	$V_{DD}$ = 17 V, $I_{DQ}$ = 300 mA, $P_{OUT}$ = 45 W, f = 870 MHz All phase angles	20:1			VSWR

### 2.3 ESD protection characteristics

Table 6. ESD protection characteristics

Test conditions	
Human body model	2
Machine model	МЗ

STAP85025 Impedance

## 3 Impedance

Figure 2. Current conventions

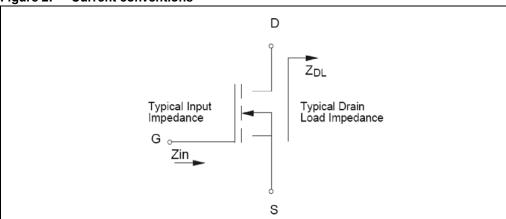


Table 7. Impedance data

Frequency (MHz)	Z <sub>IN</sub> (Ω)	<b>Z</b> <sub>DL</sub> (Ω)
870 MHz	0.21 +j 1.82	1.23 -j 0.98

### 4 Typical performances

Figure 3. Capacitances vs drain voltage

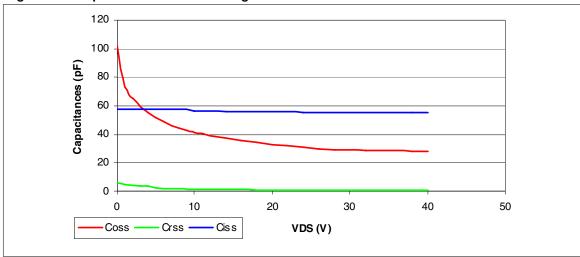


Figure 4. DC output characteristics  $(T_{amb} = -40 \, {}^{o}C)$ 

(T<sub>amb</sub> = -40 °C)

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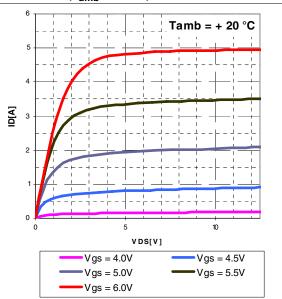
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Figure 5. DC output characteristics  $(T_{amb} = 20 \, {}^{\circ}C)$ 



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Output power and drain current vs

2

Vgs (V)

Figure 8.

0.5

1.0

Input power (W)

0.0

 $(T_{amb} = 60 \, ^{\circ}C)$ bias current Tamb = +60 °C 20 ldq = 100mA 19 Idq = 200mA Idq = 300mA 18 17 Gain (dB) ID[A] 15 14 13 Freq = 870 MHz Vdd = 13.6V 12 11 10 0 5 10 15 20 25 30 35 Output power (W) Vgs = 4.0VVgs = 4.5VVgs = 5.0V Vgs = 5.5VVgs = 6.0V

DC output characteristics Figure 6. Figure 7. Gain vs output power and

input power gate voltage 40 80 32 3.2 35 70 Freq = 870 MHz 2.8 28 Pin = 0.4W Ontbut bower (W) 25 20 15 10 60 2.4 24 Idq = 300mA50 40 30 Efficiency (%) **Mont** 16 12 2 (A) 1.6 Freq = 870 MHz 1.2 Vdd = 13.6V 10 Idq = 300 mA 20 0.8 8 5 10 Pout 0.4 -Eff Pout

Figure 9.

Ouptut power and efficiency vs

2.0

2.5

1.5

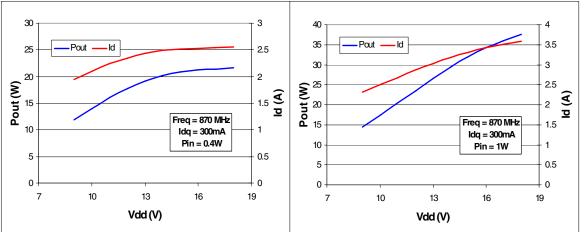
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Figure 10. Pout and drain current vs supply voltage (P<sub>in</sub> = 0.4 W)

Figure 11. Pout and drain current vs supply voltage (P<sub>in</sub> = 1 W)



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## 5 ECOPACK®

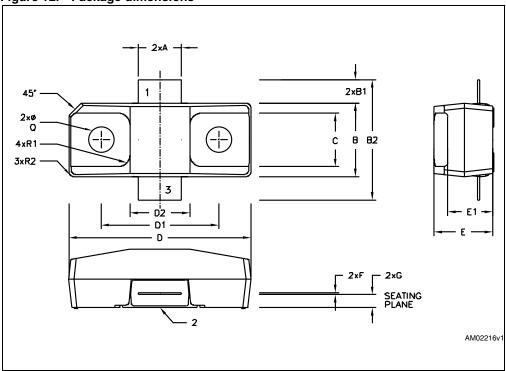
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Table 8. STAP1 mechanical data

	mm.		Inc	ch .
Dim.	Min	Max	Min	Max
Α	5.40	5.65	0.212	0.222
В	9.27	9.53	0.365	0.375
B1	2.90	3.10	0.114	0.122
B2	15.10	15.65	0.594	0.616
С	6.60	6.99	0.260	0.275
D	23.11	23.42	0.910	0.922
D1	14.88	15.19	0.586	0.598
D2	7.52	7.82	0.296	0.308
E	7.42	7.57	0.292	0.298
E1	5.69	5.84	0.224	0.230
F	0.21	0.31	0.008	0.012
G	1.62	1.72	0.064	0.068
Q	3.15	3.30	0.124	0.130
R1	1.52		0.0	60
R2	0.64		0.0	25

Figure 12. Package dimensions



STAP85025 Revision history

# 6 Revision history

Table 9. Document revision history

Date	Revision	Changes	
01-Jun-2009	1	Initial release	
02-Jul-2009	2	Deleted moisture sensitivity level table on page 4	

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